

NOT RECOMMENDED FOR NEW DESIGN **USE DMP3007LK3**



DMP3010LK3

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) max	I _D T _A = +25°C		
201/	8mΩ @ Vgs = -10V	-17A		
-30V	10.2mΩ @ V _{GS} = -4.5V	-14.5A		

Description

This new generation MOSFET has been designed to minimize the onresistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC converters
- Power management functions
- Backlighting

Features and Benefits

- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

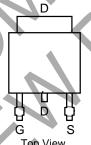
https://www.diodes.com/quality/product-definitions/

Mechanical Data

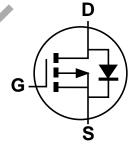
- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish—Tin Finish annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
 - Weight: 0.33 grams (Approximate)



Top View



Top View Pin-Out



Equivalent Circuit

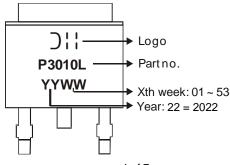
Ordering Information (Note 4)

Part Number	Prokago	Pack	Packing		
Part Number	Package	Qty.	Carrier		
DMP3010LK3-13	TO252 (DPAK)	2500	Tape & Reel		

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	VDSS	-30	V		
Gate-Source Voltage	V_{GSS}	±20	V		
Continuous Drain Current (Note C) V 40V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	ID	-17.0 -13.0	Α
Continuous Drain Current (Note 6) V _{GS} = -10V	t<10s	T _A = +25°C T _A = +70°C	ID	-27.0 -21.0	А
Continuous Drain Current (Note C) Ves 45V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	lo	-14.5 -11.5	Α
Continuous Drain Current (Note 6) V _{GS} = -4.5V	t<10s	$T_A = +25$ °C $T_A = +70$ °C	I _D	-23.0 -18.0	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	IDM	-100	Α		
Maximum Body Diode Forward Current (Note 6)	Is	5.5	Α		
Avalanche Current (Note 7)	las	47	Α		
Avalanche Energy (Note 7)	Eas	113	mJ		

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Total Power Dissipation (Note 5)			Po	1.7	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady state t<10s			72	°C/W
Thermal Resistance, Junction to Ambient (Note 3)			R _θ JA	29	°C/W
Total Power Dissipation (Note 6)			PD	3.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady	state	5	37	°C/W
Thermal Resistance, Junction to Ambient (Note o)	t<10	S	$R_{\theta JA}$	15	°C/W
Operating and Storage Temperature Range			TJ, TSTG	-55 to +150	ů

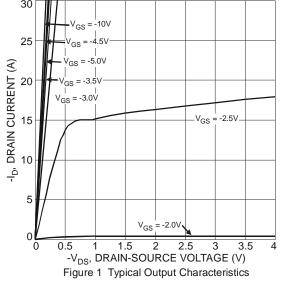
Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

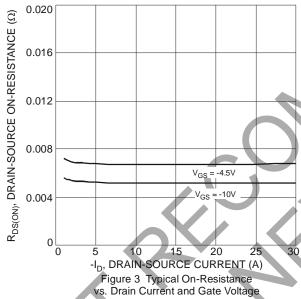
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BVDSS	-30	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	V -/	_	-1	μΑ	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	-1.1	-1.6	-2.1	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance		_	6.5	8	mΩ	$V_{GS} = -10V, I_{D} = -10A$	
Static Dialii-Source Oil-Resistance	RDS(ON)	_	7.2	10.2	11177	$V_{GS} = -4.5V, I_{D} = -10A$	
Forward Transfer Admittance	Yfs	_	30	_	S	$V_{DS} = -15V, I_{D} = -10A$	
Diode Forward Voltage	VsD	_	-0.65	-1.0	V	$V_{GS} = 0V$, $I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	6234	_		V _{DS} = 15V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss	_	1500	_	pF		
Reverse Transfer Capacitance	Crss	_	774	_		1 = 1.0IVII IZ	
Gate Resistance	Rg	_	1.28	_	μ	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$	
Total Gate Charge	Qg	_	59.2	_		45)/)/ 45)/	
Gate-Source Charge	Qgs	_	16.1	_	nC	$V_{DS} = -15V, V_{GS} = -4.5V,$	
Gate-Drain Charge	Qgd	_	15.7	_		I _D = -10A	
Turn-On Delay Time	t _{D(on)}	_	11.4	_			
Turn-On Rise Time	tr	_	9.4	_		V _{DS} = -15V, V _{GEN} = -10V,	
Turn-Off Delay Time	t _{D(off)}	_	260.7	_	ns	$R_G = 6\Omega$, $I_D = -1A$	
Turn-Off Fall Time	tf	_	99.3	_			

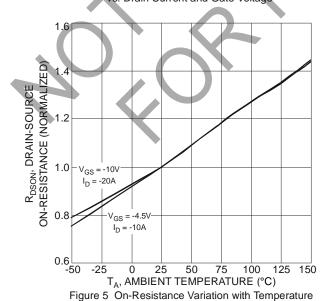
Notes:

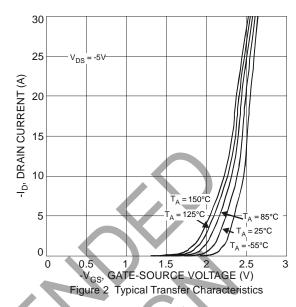
- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
- 7. UIS in production with L = 0.1 mH, $T_J = +25 ^{\circ}\text{C}$.
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to production testing.

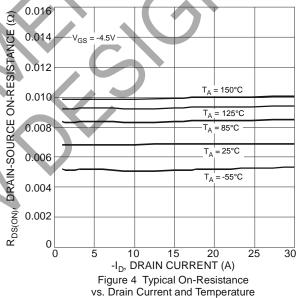












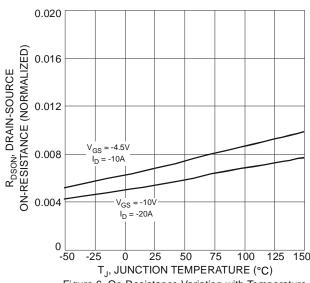


Figure 6 On-Resistance Variation with Temperature



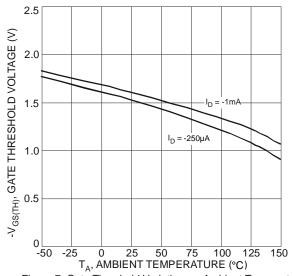
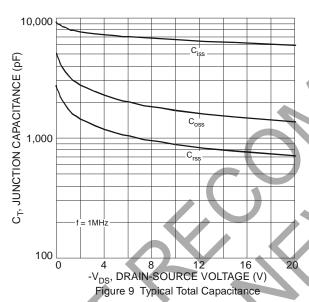


Figure 7 Gate Threshold Variation vs. Ambient Temperature



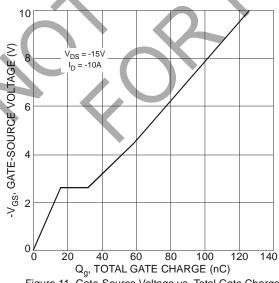
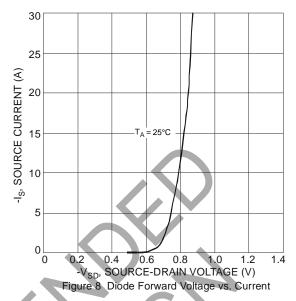


Figure 11 Gate-Source Voltage vs. Total Gate Charge



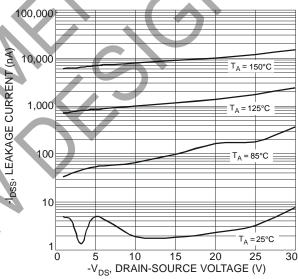


Figure 10 Typical Leakage Current vs. Drain-Source Voltage

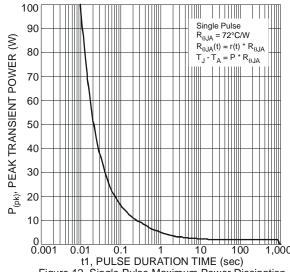
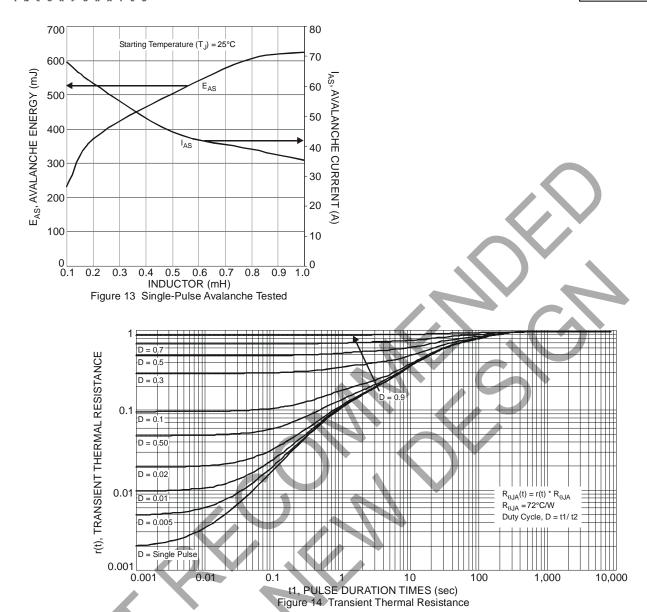


Figure 12 Single Pulse Maximum Power Dissipation

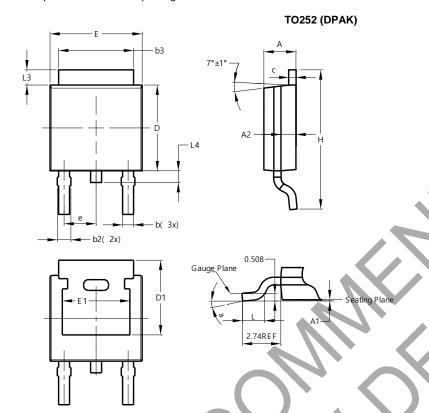






Package Outline Dimensions

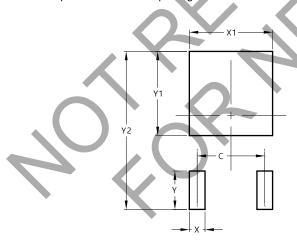
Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
ਰ	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b 3	5.21	5.46	5.33		
O	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21		1		
е	1	4	2.286		
Ш	6.45	6.70	6.58		
E1	4.32	1	_		
Ŧ	9.40	10.41	9.91		
F	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	_		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Υ	2.600
Y1	5.700
Y2	10 700

TO252 (DPAK)

March 2022



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